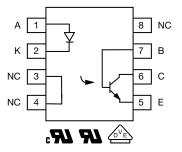


Vishay Semiconductors

Optocoupler, Phototransistor Output, Low Input Current, With Base Connection





LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The VO215AT, VO216AT, VO217AT are optically coupled pairs with a Gallium Arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. The high CTR at low input current is designed for low power consumption requirements such as CMOS microprocessor interfaces.

FEATURES

- High current transfer ratio
- Isolation test voltage, 4000 V_{RMS}
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



RoHS

AGENCY APPROVALS

- <u>UL</u>
- <u>cUL</u>
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1

ORDERING INFORMATION			
V O 2 PART	SOIC-8		
AGENCY CERTIFIED / PACKAGE		CTR (%)	
UL, cUL, VDE	≥ 20	≥ 50	≥ 100
SOIC-8	VO215AT	VO216AT	VO217AT



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PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT		L L		1
Peak reverse voltage		V _R	6	V
Peak forward current	1 µs, 300 pps	I _{FM}	1	A
Forward continuous current		l _F	60	mA
Power dissipation		P _{diss}	90	mW
Derate linearly from 25 °C			1.2	mW/°C
OUTPUT				
Collector emitter breakdown voltage		BV _{CEO}	30	V
Emitter collector breakdown voltage		BV _{ECO}	7	V
Collector base breakdown voltage		BV _{CBO}	70	V
I _{Cmax. DC}		I _{Cmax. DC}	50	mA
I _{Cmax.}	t < 1 ms	I _{Cmax.}	100	mA
Power dissipation		P _{diss}	150	mW
Derate linearly from 25 °C			2	mW/°C
COUPLER				
Isolation test voltage	1 s	V _{ISO}	4000	V _{RMS}
Total package dissipation	LED and detector	P _{tot}	240	mW
Derate linearly from 25 °C			3.2	mW/°C
Storage temperature		T _{stg}	-40 to +150	°C
Operating temperature		T _{amb}	-40 to +100	°C
Soldering time	At 260 °C		10	S

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT	1					
Forward voltage	I _F = 1 mA	V _F	-	1	1.5	V
Reverse current	V _R = 6 V	I _R	-	0.1	100	μA
Capacitance	V _R = 0 V	Co	-	13	-	pF
OUTPUT						
Collector emitter breakdown voltage	I _C = 100 μA	BV _{CEO}	30	-	-	V
Emitter collector breakdown voltage	I _C = 10 μA	BV _{ECO}	7	-	-	V
Collector base breakdown voltage	I _C = 100 μA	BVCBO	100	-	-	V
Collector base current		ICBO	-	-	1	nA
Emitter base current		I _{EBO}	-	-	1	nA
Dark current collector emitter	$V_{CE} = 10 \text{ V}, \text{ I}_{F} = 0 \text{ A}$	I _{CEO}	-	5	50	nA
Collector emitter capacitance	$V_{CE} = 0$	C _{CE}	-	10	-	pF
Saturation voltage, collector emitter	I _F =1 mA, I _C = 0.1 mA	V _{CEsat}	-		0.4	V
COUPLER						
Capacitance (input to output)		CIO	-	0.5	-	pF

Note

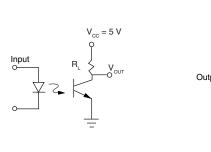
• Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

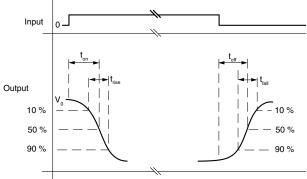


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CURRENT TRANSFER RATIO ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		VO215AT	CTR _{DC}	20	50	-	%
DC current transfer ratio	$I_{F} = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	VO216AT	CTR _{DC}	50	80	-	%
		VO217AT	CTR _{DC}	100	130	-	%

SWITCHING CHARACTERISTICS ($T_{amb} = 25 \text{ °C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	I_{C} = 2 mA, R_{L} = 100 Ω , V_{CC} = 10 V	t _{on}	-	3	-	μs
Turn-off time	I_{C} = 2 mA, R_{L} = 100 Ω , V_{CC} = 10 V	t _{off}	-	3	-	μs
Rise time	I_{C} = 2 mA, R_{L} = 100 Ω , V_{CC} = 10 V	t _r	-	3	-	μs
Fall time	I_{C} = 2 mA, R_{L} = 100 Ω , V_{CC} = 10 V	t _f	-	2	-	μs

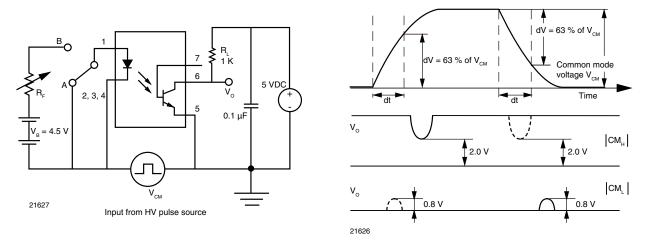




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Fig. 1 - Switching Test Circuit

COMMON MODE TRANSIENT IMMUNITY							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Common mode transient immunity at logic high	V_{CM} = 1000 V _{P-P} , R _L = 1 kΩ, I _F = 0 mA	C _{MH}	-	5000	-	V/µs	
Common mode transient immunity at logic low	V_{CM} = 1000 V_{P-P} , R_L = 1 k Ω , I_F = 10 mA	C _{ML}	-	5000	-	V/µs	





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PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)			-	40 / 100 / 21	-	
Polution degree			-	2	-	
Comparative tracking index		CTI	175	-	399	
Isolation test voltage	1 s	V _{ISO}	4000	-	-	V _{RMS}
Peak transient overvoltage		V _{IOTM}	6000	-	-	V
Peak insulation voltage		V _{IORM}	560	-	-	V
Resistance (input to output)		R _{IO}	-	100	-	GΩ
Safety rating - power output		P _{SO}	-	-	350	mW
Safety rating - input current		I _{SI}	-	-	150	mA
Safety rating - temperature		T _{SI}	-	-	165	°C
External creepage distance			4	-	-	mm
External clearance distance			4	-	-	mm
Internal creepage distance			3.3	-	-	mm
Insulation thickness			0.2	-	-	mm

Note

• As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

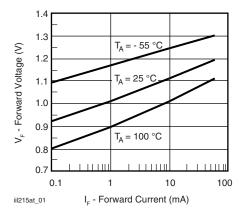


Fig. 3 - Forward Voltage vs. Forward Current

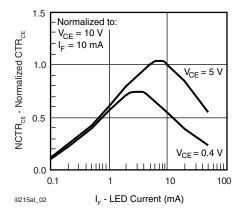


Fig. 4 - Normalized Non-Saturated and Saturated $\mbox{CTR}_{\mbox{CE}}$ vs. LED Current

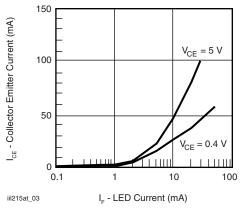


Fig. 5 - Collector Emitter Current vs. LED Current

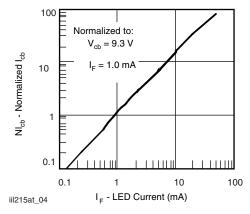


Fig. 6 - Normalized Collector Base Photocurrent vs. LED Current

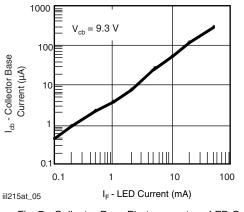


Fig. 7 - Collector Base Photocurrent vs. LED Current

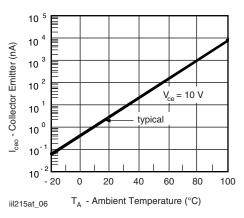


Fig. 8 - Collector Emitter Leakage Current vs. Temperature

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2.0 70 °C Normalized to: 50 °C $Ib = 20 \ \mu A$ Nh_{FE(sat)} - Normalized 1.5 $V_{ce} = 10 V$ Saturated h_{FE} 1.0 0.4 V 0.5 11111 11111 111111 0.0 10 100 1000 iil215at_07 I_b - Base Current (μA)

Fig. 9 - Normalized Saturated h_{FF} vs. Base Current and Temperature

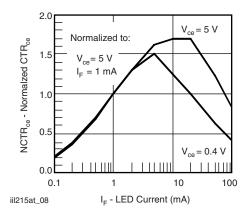
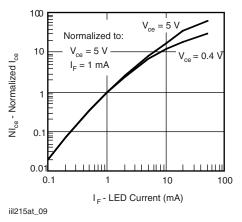
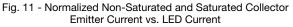


Fig. 10 - Normalized Non-Saturated and Saturated CTR_{CE} vs. LED Current







VO215AT, VO216AT, VO217AT

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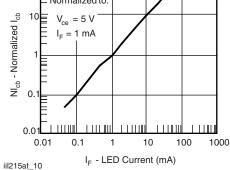


Fig. 12 - Normalized Collector Base Photocurrent vs. LED Current

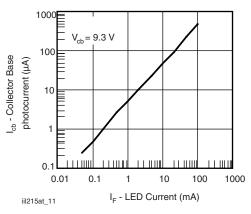


Fig. 13 - Collector Base Photocurrent vs. LED Current

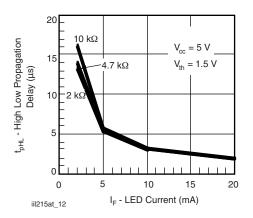


Fig. 14 - High to Low Propagation Delay vs. LED Current and Load Resistor

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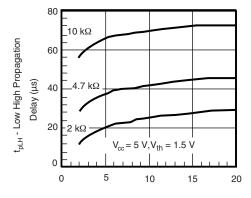
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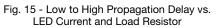
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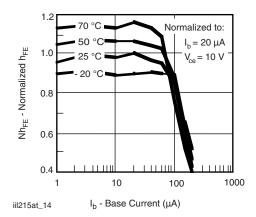


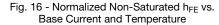
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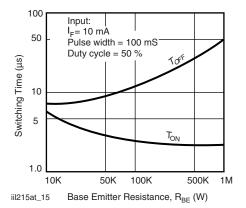


Fig. 17 - Typical Switching Characteristics vs. Base Resistance (Saturated Operation)

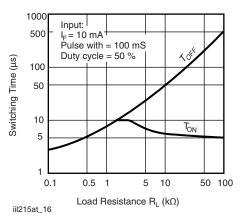


Fig. 18 - Typical Switching Times vs. Load Resistance

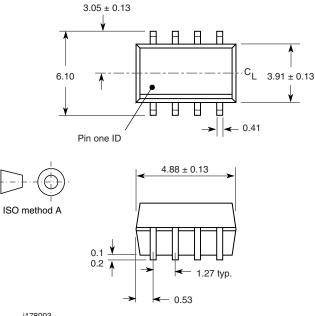
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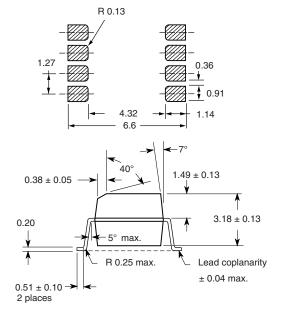
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PACKAGE DIMENSIONS in millimeters





i178003

PACKAGE MARKING (Example)



Fig. 19 - Example of VO215AT

Notes

- XXXX = LMC (lot marking code) .
- Tape and reel suffix (T) is not part of the package marking ٠



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